# N-Channel 30-V (D-S) MOSFET

### **Key Features:**

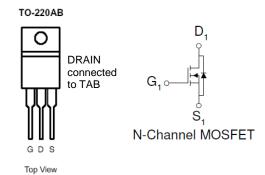
- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

# **Typical Applications:**

- Automotive Systems
- DC/DC Conversion Circuits
- Battery Powered Power Tools

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
30	$3.5 @ V_{GS} = 10V$	90 <sup>a</sup>	
30	4.6 @ V <sub>GS</sub> = 4.5V	90"	





ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage			30	V		
Gate-Source Voltage		$V_{GS}$	±20	1 <sup>v</sup>		
Continuous Drain Current a	T <sub>C</sub> =25°C	I <sub>D</sub>	90	Α		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub> 360		<b>A</b>		
Continuous Source Current (Diode Conduction) <sup>a</sup> T <sub>C</sub> =25°C		I <sub>S</sub>	90	Α		
Power Dissipation <sup>a</sup>	T <sub>C</sub> =25°C	$P_{D}$	300	W		
Operating Junction and Storage Temperature Range	,	$T_J, T_{stg}$	-55 to 175	°C		

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W
Maximum Junction-to-Case	$R_{\theta JC}$	0.5	C/VV

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#### Notes

- a. Package Limited
- b. Pulse width limited by maximum junction temperature

### **Electrical Characteristics**

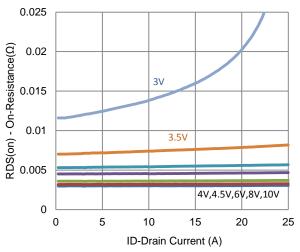
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zoro Coto Voltogo Droin Correct		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	пΛ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	120			Α	
Drain-Source On-Resistance <sup>a</sup>	l r	$V_{GS} = 10 \text{ V}, I_D = 45 \text{ A}$			3.5	mΩ	
	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 44 \text{ A}$			4.6		
Forward Transconductance a	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_{D} = 20 \text{ A}$		20		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 45 A, V <sub>GS</sub> = 0 V		0.92		V	
	Dynamic <sup>b</sup>						
Total Gate Charge	$Q_g$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 20 \text{ A}$		36		nC	
Gate-Source Charge	$Q_gs$			12			
Gate-Drain Charge	$Q_gd$			13			
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DS}$ = 15 V, $R_{L}$ = 0.8 Ω, $I_{D}$ = 20 A, $V_{GEN}$ = 10 V, $R_{GEN}$ = 6 Ω		12		ns	
Rise Time	t <sub>r</sub>			15			
Turn-Off Delay Time	$t_{d(off)}$			89			
Fall Time	t <sub>f</sub>			30			
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 Mhz		6725			
Output Capacitance	C <sub>oss</sub>			466		pF	
Reverse Transfer Capacitance	$C_{rss}$			397			

#### Notes

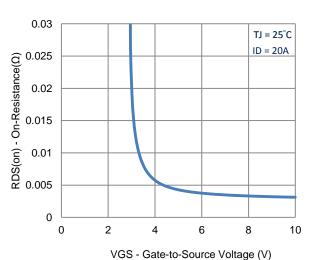
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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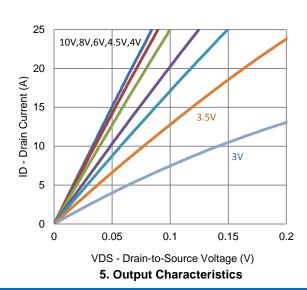
## **Typical Electrical Characteristics**



#### 1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage

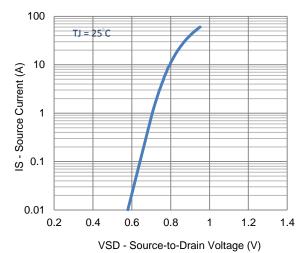


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TJ = 25°C

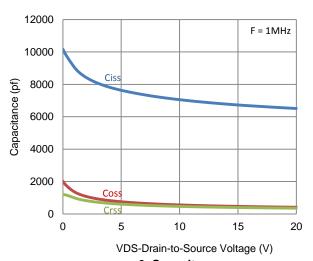
(Y) tuent 10
0 0 1 2 3 4 5

VGS - Gate-to-Source Voltage (V)

2. Transfer Characteristics

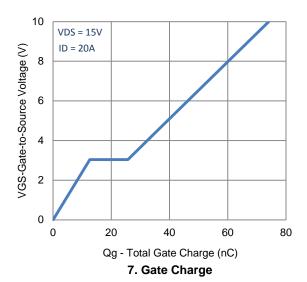


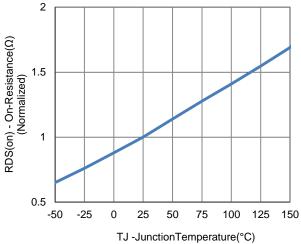
4. Drain-to-Source Forward Voltage

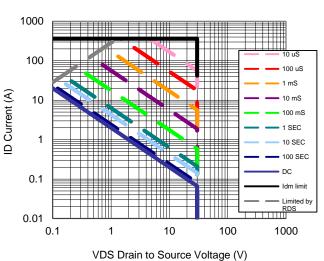


6. Capacitance

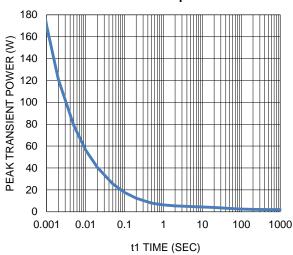
## **Typical Electrical Characteristics**





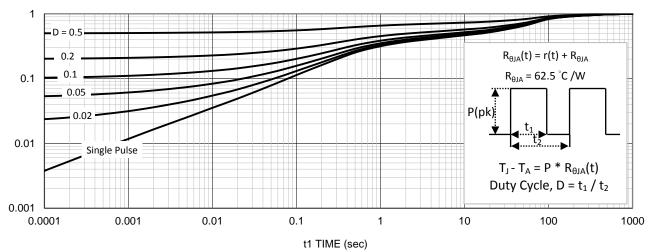






9. Safe Operating Area

10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

# **Package Information**

